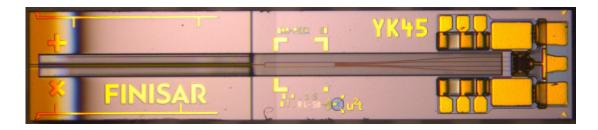
50 GHz HIGH POWER PHOTODIODE

CHPDV21x0R

The CHPDV21x0R is an advanced waveguide photodetector chip integrated with a Bias-Tee. The High-Power Photodiode utilizes a mode-converting tapered waveguide for efficient fiber-to-chip coupling and a 1×4 Multi-Mode Interference (MMI) Coupler. The optical signal is split by the MMI coupler into 4 equal parts and then it is fed into an array of 4 photodiodes which are connected in-parallel.

It has a responsivity of 0.5 A/W at 1550 nm and a high saturation photocurrent of 30 mA at 20 GHz. The CHPDV21x0R can deliver 4.5 dBm RF output power at 20 GHz and 1.5 dBm at 50 GHz. The device exhibits a high linearity with typical OIP3 values above 20 dBm at a frequency of 40 GHz.



Picture shows product example, actual product might differ

FEATURES

- High 3dB bandwidth of 50 GHz
- Optical window at 1550 nm
- Excellent linearity
- High responsivity of >0.45 A/W (typ.)
- Low PDL of < 0.5 dB (typ.)
- 4.5 dBm RF output power at 20 GHz
- High Linearity (25 dBm OIP3 at 40 GHz)

APPLICATIONS

- Microwave Photonics
- Analog Photonics
- Radio over Fiber



50 GHz HIGH POWER PHOTODIODE

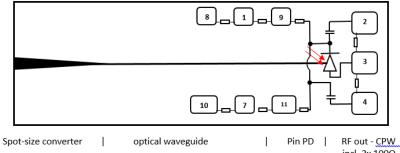
Product Selection

CHPDV21x0R

X	2	= Standard version
	3	= Low reflection coefficient

Block Diagram

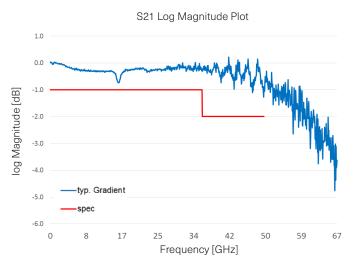
Bias Pads incl. R Bias | MIM Capacitors



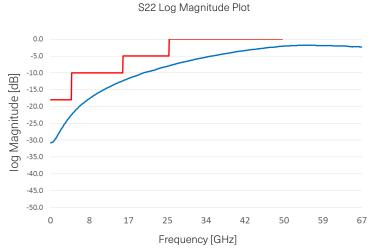
incl. 2x 100Ω (eff. 50 Ω)

Key Specifications

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating Case Temperature	T _{CASE}		0		75	°C
Storage Temperature	T _{STORE}		-40		125	°C
Wavelength Range	λ			1550		nm
Photodiode Supply Voltage	V _{PD}			4.0		V
Average Optical Input Power	P _{OPT_avg}	At facet			18	dBm
Photodiode DC Responsivity	R		0.4			A/W
Polarization-Dependent Loss	PDL				0.5	dB
Photodiode Dark Current	I _{DARK}	T _{CASE} = 25 °C		5		nA
3 dB Cut-off Frequency	f _{3dB}		50			GHz
Output Reflection Coefficient	S ₂₂	CHPDV2120R CHPDV2130R			0 -8	dB



Typical frequency response s₂₁



Typical backreflection s_{22} for standard version

